

FEATURES

- Si active devices
- Power gain@30dB
- Low distortion
- Excellent linear gain
- Low noise figure
- High reliability
- Low cost

DESCRIPTION

The SMG2301R is a hybrid reverse amplifier module. The part employs Si dies and is operated from 5 MHz to 200MHz with supply voltage +12V(DC)

OUTLINE

PINCONFIGURATION

Pin	Description
1	Input
5	+V _B
9	Output
2、3、7、8	GND

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNITS
G _p	Power Gain	f=10 MHz	30	31.5	dB
I _{tot}	Total current consumption(DC)	V _B =12V	260	290	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System

SYMBOL	PARAMETER	MIN.	MAX.	UNITS
V _i	RF input voltage	-	65	dBmV
T _{stg}	Storage temperature	-40	+100	°C
T _{mb}	Operating mounting base temperature	-20	+90	°C

SANLAND TECHNOLOGY

·Tel: 86-0755-28968333
·Fax: 86-0755-89724455
·2021.3

·Http: www.sanlandtech.com
·E-mail: info@sanlandtech.com

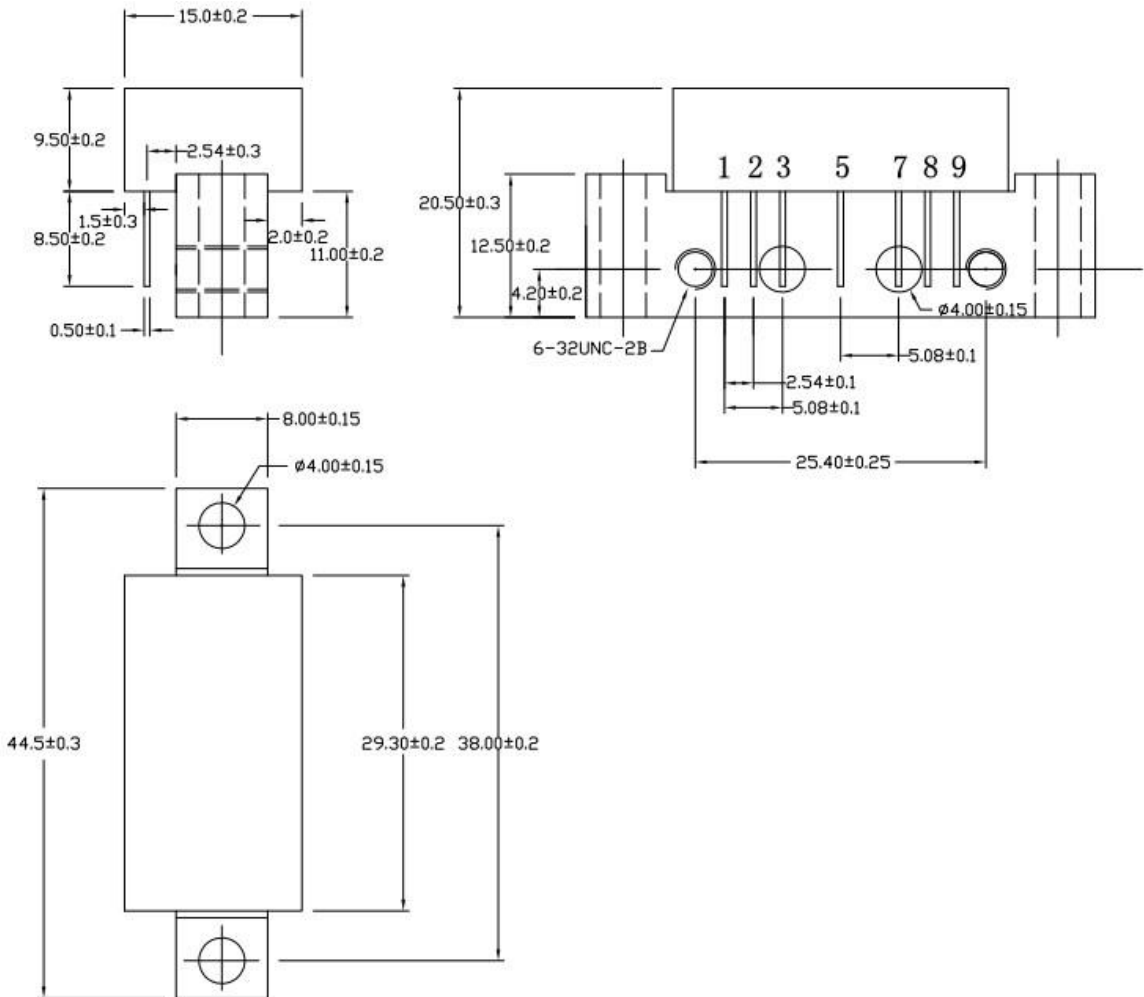
CHARACTERISTICS

(Bandwidth 5 to 200MHz; $T_{mb}=25^{\circ}\text{C}$, $V_B=12\text{V}$, $Z_S=Z_L=75\Omega$)

SYMBOL	PARAMETER	UNIT	MIN.	TYP.	MAX.	CONDITIONS
G_p	Power Gain	dB	30	-31	31.5	$f=10\text{MHz}$
SL	Slope cable equivalent	dB	-0.5	-	+0.5	$f=5$ to 200MHz
FL	Flatness of frequency response	dB	-	-	± 0.3	$f=5$ to 200MHz
S_{11}	Input Return Loss	dB	-	-	-18	$f=5$ to 200MHz
S_{22}	Output Return Loss	dB	-	-	-18	$f=5$ to 200MHz
CTB	Composite Triple Beat	dB	-	-	-62	17 channels ; $V_O=50\text{dBmV}$ CTB measured at 77.25 MHz
CSO	Composite Second Order distortion	dB	-	-	-63	
X_{mod}	Cross Modulation	dB	-	-	-62	CSO measured at 78.5 MHz;
F	Noise Figure	dB	-	4	-	$f=200$ MHz
I_{tot}	Total Current Consumption	mA	260	290		$V_B=+12\text{V}$

The module normally operates at $V_B=12\text{ V}(\pm 0.5)$,

MODULE DIMENSIONS



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